



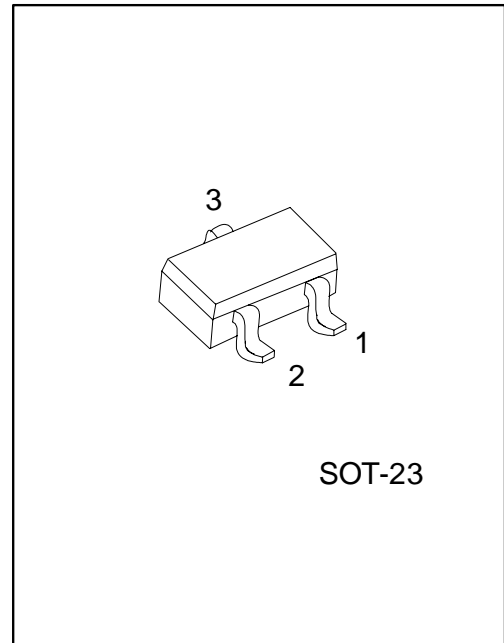
MMBT1616/A

NPN SILICON TRANSISTOR

NPN EPITAXIAL SILICON TRANSISTOR

■ DESCRIPTION

- * Audio frequency power amplifier
- * Medium speed switching



*Pb-free plating product number:
MMBT1616L/MMBT16AL

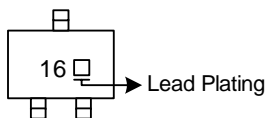
■ ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Normal	Lead Free Plating		1	2	3	
MMBT1616-x-AE3-R	MMBT1616L-x-AE3-R	SOT-23	E	B	C	Tape Reel
MMBT1616A-x-AE3-R	MMBT1616AL-x-AE3-R	SOT-23	E	B	C	Tape Reel

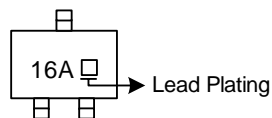
<p>MMBT1616L-x-AE3-R</p>	<p>(1) R: Tape Reel</p> <p>(2) AE3: SOT-23</p> <p>(3) x: refer to Classification of h_{FE1}</p> <p>(4) L: Lead Free Plating, Blank: Pb/Sn</p>
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■ MARKING

UTC MMBT1616



UTC MMBT1616A



MMBT1616/A

NPN SILICON TRANSISTOR

■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	1616	60	V
	1616A	120	V
Collector-Emitter Voltage	1616	50	V
	1616A	60	V
Emitter to Base Voltage	V_{EBO}	6	V
Collector Current	DC	1	A
	Pulse*	2	A
Total Power Dissipation ($T_a=25$)	P_C	350	mW
Junction Temperature	T_J	+150	
Storage Temperature	T_{STG}	-55 ~ +150	

Note (*) Pulse width \leq 10ms, Duty cycle $<$ 50%

1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

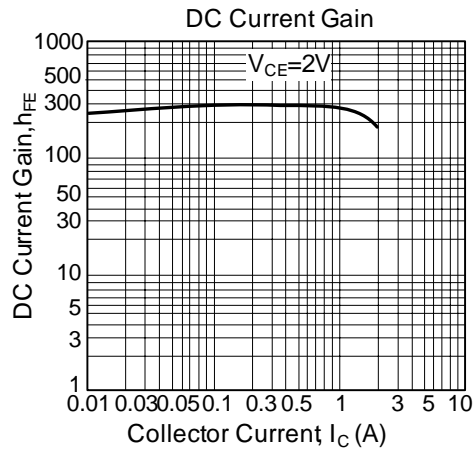
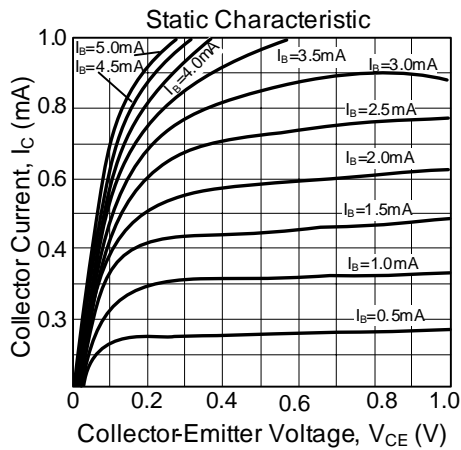
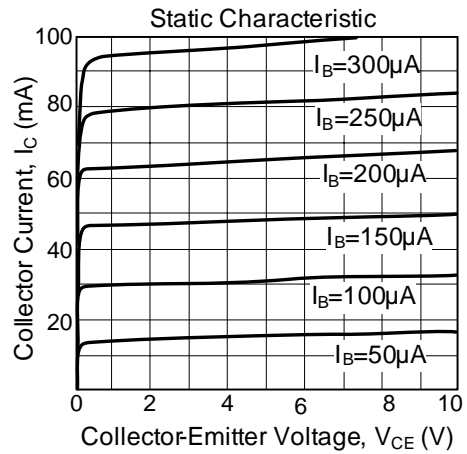
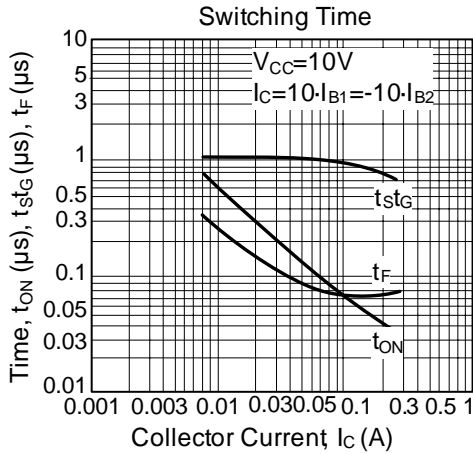
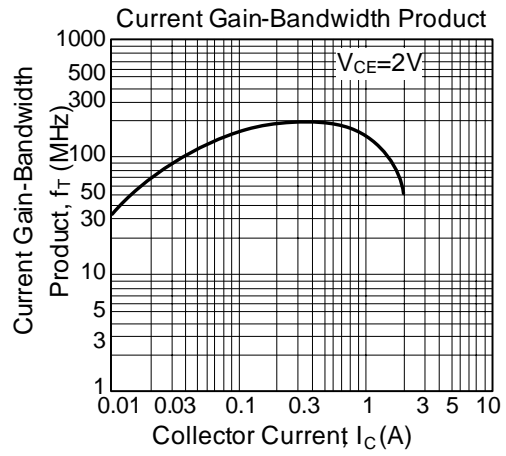
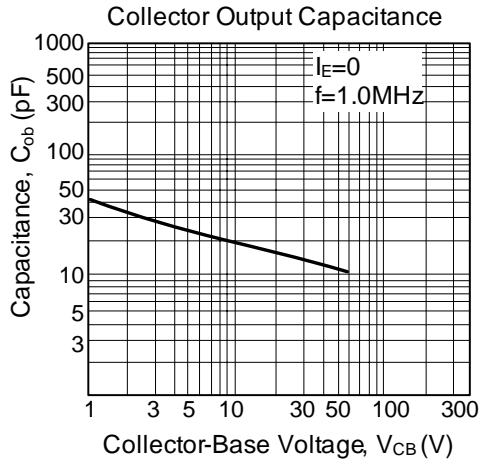
■ ELECTRICAL CHARACTERISTICS ($T_a=25$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current	I_{CBO}	$V_{CB}=60V$			100	nA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=6V$			100	nA
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=1A, I_B=50mA$		0.15	0.3	V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=1A, I_B=50mA$		0.9	1.2	V
Base Emitter On Voltage	$V_{BE(ON)}$	$V_{CE}=2V, I_C=50mA$	600	640	700	mV
DC Current Gain	h_{FE1}	$V_{CE}=2V, I_C=100mA$	135		600	
	h_{FE2}	$V_{CE}=2V, I_C=1A$	81		400	
Current Gain Bandwidth Product	f_T	$V_{CE}=2V, I_C=100mA$	100	160		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$			19	pF
Turn On Time	t_{ON}	$V_{CE}=10V, I_C=100mA$		0.07		us
Storage Time	t_S	$I_{B1}=-I_{B2}=10mA$		0.95		us
Fall Time	t_F	$V_{BE(OFF)}=-2 \sim -3V$		0.07		us

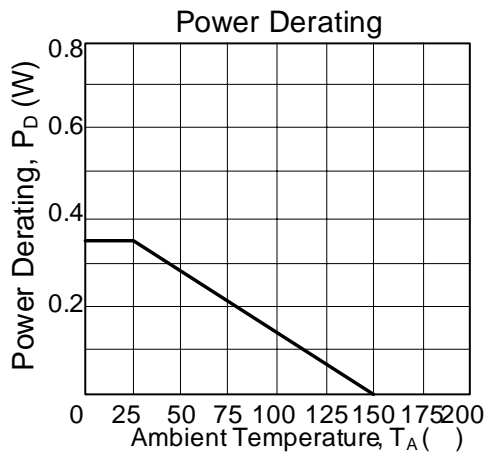
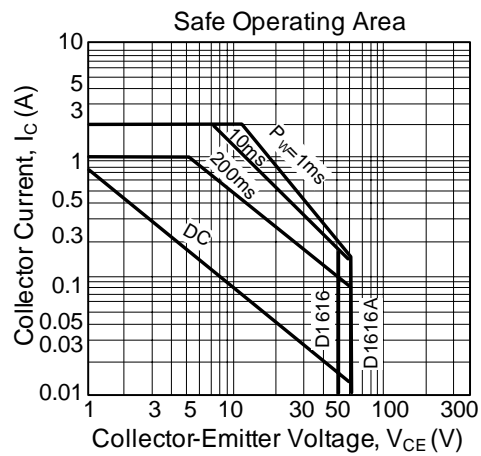
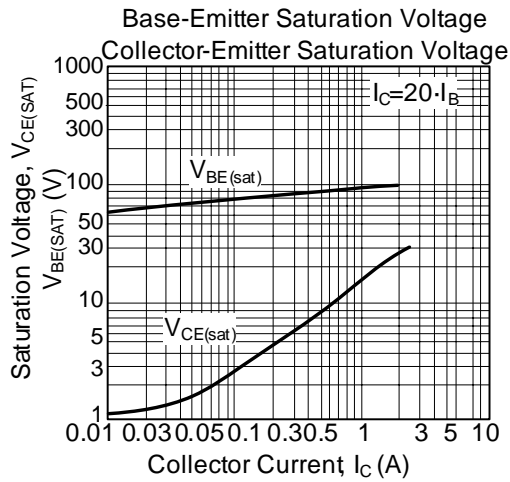
■ CLASSIFICATION OF h_{FE1}

RANK	Y	G	L
h_{FE1}	135-270	200-400	300-600

■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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